

Supplementary Information (ESI):

An Ultraviolet-Induced Ostwald Ripening Strategy towards Mesoporous Ga₂O₃/GaOOH Heterojunction Composite with Controllable Structures for Enhanced Photocatalytic Hydrogen Evolution

Yuenan Zheng,^[a] Meihong Fan,^[a] Kaiqian Li,^[a] Rui Zhang,^[a] Xuefeng Li,^[c] Ling Zhang,^[b] and Zhen-An Qiao*^[a]

^a State Key Laboratory of Inorganic Synthesis and Preparative Chemistry, International Joint Research Laboratory of Nano-Micro Architecture Chemistry, College of Chemistry, Jilin University, Changchun 130012, China

^b State Key Laboratory of Supramolecular Structure and Materials, College of Chemistry, Jilin University, 2699 Qianjin Street, Changchun 130012, China

^c Alan G. MacDiarmid Institute, College of Chemistry, Jilin University, 2699 Qianjin Street, Changchun 130012, China

E-mail: qiaozhenan@jlu.edu.cn

1. Experimental procedure

1.1. Materials

Gallium(III) nitrate hydrate (Sinopharm Chemical Reagent Co., Ltd.), isopropanol, Ethanol and glycerol (Beijing Chemical Factory), Deionized water (18.2 MΩ·cm resistivity) was obtained via a PALL PURELAB Plus system in laboratory.

1.2. Preparation of gallium alkoxide (Ga-gly) microsphere

Firstly, 0.328 g gallium nitrate hydrate and 10 g glycerol were dissolved in isopropanol (30 mL), forming a homogeneous solution. Next, the solution was transferred into a Teflon-lined autoclave and heated at 180 °C for 3 h. After cooling down, the white precipitate was separated and washed several by ethanol and finally dried at 65 °C for 12 h in an oven.

1.3. Preparation of mesoporous Ga₂O₃ microspheres

In order to obtain mesoporous Ga₂O₃ microspheres, the Ga-gly was calcined at different temperatures (450, 600 or 700 °C, respectively) for 3 h in a muffle furnace in air with a heating rate of 2 °C/min, labelled as Meso-Ga₂O₃-X, where X was the calcination temperature.

1.4. Preparation of mesoporous Ga₂O₃/GaOOH heterojunction composite and GaOOH sample

40 mg of the Meso-Ga₂O₃-600 sample was dispersed in 50 mL deionized water and then irradiated under UV light for 3 h at room temperature. The UV-light source was a 500 W mercury-arc lamp. After UV irradiation, the result sample was washed with ethanol and dried in an oven at 65 °C for 12 h. This resulting powdered sample was denoted as Ga₂O₃/GaOOH heterojunction composite. While the Meso-Ga₂O₃-450 was irradiated for 4h at identical condition, the fusiform GaOOH sample was obtained.

1.5 Preparation of bulk Ga₂O₃

0.5 g gallium nitrate hydrate was directly calcined in air at 900 °C for 3h with 2 °C/min.

2. Characterization

Powder X-ray diffraction (XRD) results were collected on a Rigaku 2550 (Japan) diffractometer with Cu Kα radiation ($\lambda = 1.5418 \text{ \AA}$). The morphologies and structures of the samples were characterized by SEM (JEOL JSM 6700F), TEM, high resolution TEM, EDX (Philips-FEI Tecnai G2S-Twin microscope equipped with a field emission gun operating at 200 kV) and STEM (Talos F200x). N₂ adsorption/desorption isotherms and pore size distribution curves were determined by Brunauer-Emmett-Teller (BET) measurement by using a Quanta 4200e surface area analyzer. The X-ray photoelectron spectroscopy (XPS) results were obtained by ESCALAB 250 X-ray photoelectron spectrometer with a monochromatic X-ray source (Al Kα radiation). And the Shimadzu UV-2450 spectrometer, Renishaw, Perkin-Elmer 580B and Hitachi F-7000 spectrophotometer were applied to obtained UV-vis spectra, Raman spectra, Fourier transform infrared spectra (FT-IR) and Photoluminescence spectra (PL) results, respectively.

2.1 Photocatalytic and photoelectrochemical activity test

The photocatalytic H₂ production experiments were performed in a Pyrex reaction cell with a top quartz window and a 500 W mercury-arc lamp as a light source. A total of 40 mg photocatalyst was suspended in a 50 mL solution including 40 mL H₂O and 10 mL methanol as sacrificial agents. Before the irradiation, the reactor was evacuated several times to remove air dissolved in the water. The generated hydrogen was analyzed by an online gas chromatograph. Cycling experiments were carried out under the same condition.

2.2 Photoelectrochemical Performance

The photoelectrochemical performance of samples were carried out by using a three-electrode CHI 660E electrochemical workstation with the mesoporous Ga₂O₃/GaOOH heterojunction composite, Ga₂O₃ and GaOOH respectively used as working electrodes, saturated calomel electrode (SCE) as reference electrode, and Pt foil as counter electrode in a 0.5 M Na₂SO₄ electrolyte. The working electrode was prepared by dropping the catalyst mixture containing 20 mg of powder and 200 μL of ethanol onto fluoride-tin oxide (FTO) glass (0.5 cm × 0.5 cm), then dried in air. And a 500 W mercury-arc lamp was employed as light source.

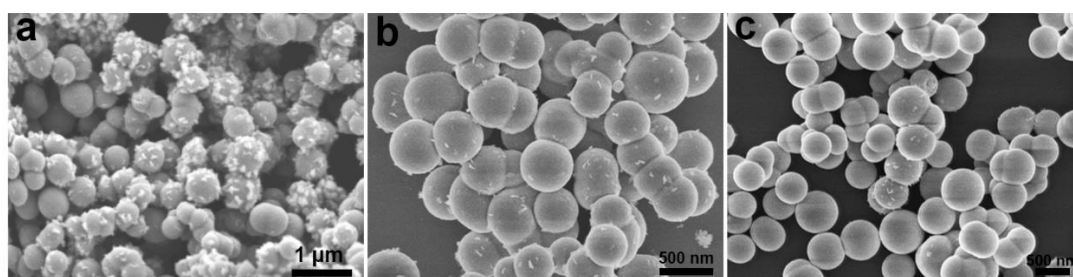


Figure S1. SEM images of Meso-Ga₂O₃-450; Meso-Ga₂O₃-600 and Meso-Ga₂O₃-700 microspheres.

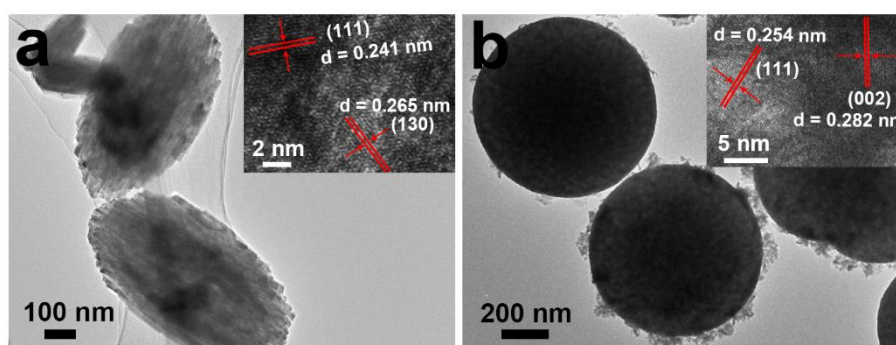


Figure S2. TEM images of GaOOH and Ga₂O₃. Insets are high magnification TEM images of them.

Table S1. The detailed pore structural data for samples.

Sample	$S_{\text{BET}}^{\text{a}}$ ($\text{m}^2 \text{g}^{-1}$)	Pore size (nm)	V_{T}^{b} ($\text{cm}^3 \text{g}^{-1}$)
Meso-Ga ₂ O ₃ -450	89.015	8.145	0.301
Meso-Ga ₂ O ₃ -600	89.223	6.794	0.149

Meso-Ga₂O₃-700	51.173	9.416	0.149
GaOOH	106.932	4.887	0.158
mesoporous Ga₂O₃/GaOOH heterojunction composite	111.493	6.079	0.202
Ga₂O₃	51.173	9.416	0.149

^a S_{BET}: specific surface area obtained from N₂ adsorption data in the P/P_0 range from 0.05 to 0.20. ^b V_T: total pore volume calculated from adsorption isotherm at $P/P_0 = 0.99$.

Table S2. The oxygen species and percentages of each peak in fitting results of O 1s XPS spectra of samples.

Sample oxygen species	Relative percentage (%)		
	O ²⁻	O _c	O _{OH}
GaOOH	33.545	14.875	51.579
Mesoporous GaOOH/Ga ₂ O ₃ heterojunction composite	27.185	36.672	36.143
Ga ₂ O ₃	37.837	62.163	—

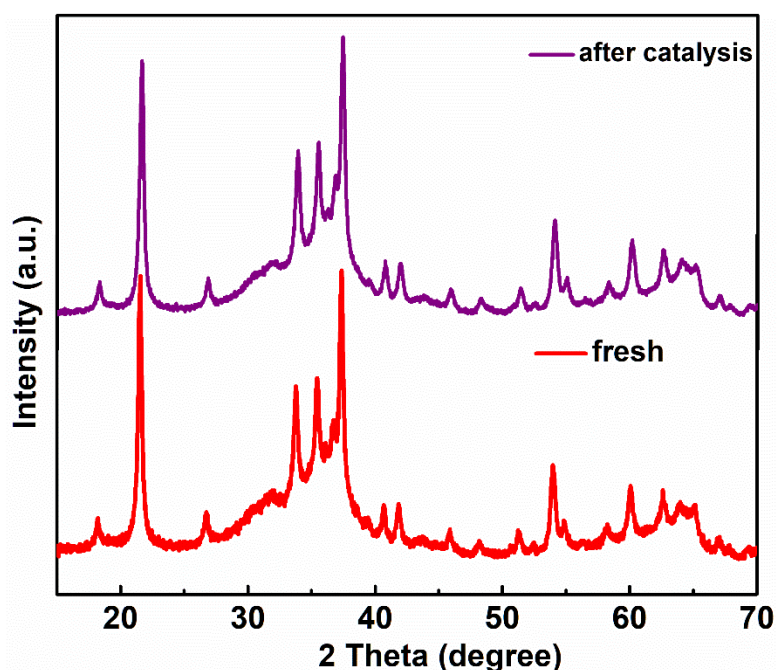


Figure S3. The XRD patterns of mesoporous Ga₂O₃/GaOOH heterojunction composite before (fresh) and after (after catalysis) photocatalytic H₂ evolution test.

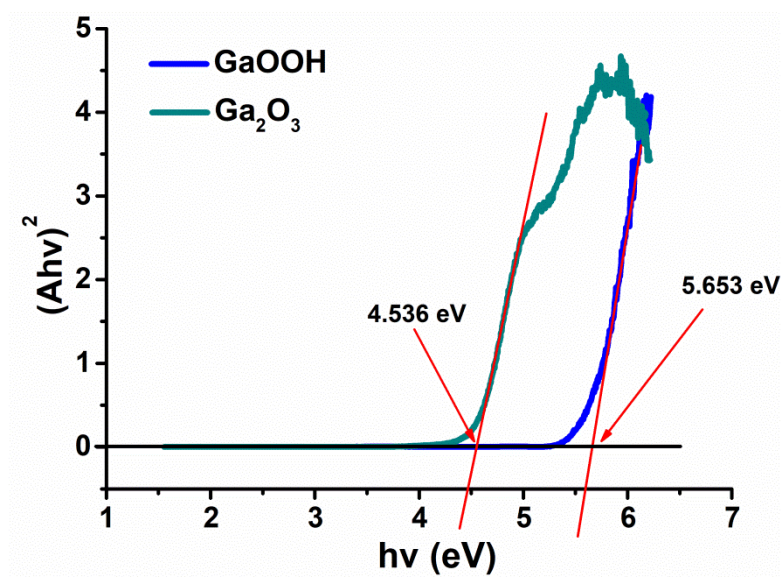


Figure S4. Bandgap energies of GaOOH and Ga₂O₃ estimated from the UV/Vis diffuse reflectance spectra by the Kubelka-Munk method.